

Ultra-Small, Ultra-Low Power MEMS Oscillator

Features

- Wide Frequency Range: 2 kHz to 80 MHz
- Ultra-Low Power Consumption: 1.3 mA/1 µA (Active/Standby)
- Ultra-Small Footprints
 - 1.6 mm x 1.2 mm
 - 2.0 mm x 1.6 mm
 - 2.5 mm x 2.0 mm
- Frequency Select Input Supports Two Pre-Defined Frequencies
- High Stability: ±20 ppm, ±25 ppm, ±50 ppm
- Wide Temperature Range
 - Automotive: -40°C to +125°C
 - Ext. Industrial: -40°C to +105°C
 - Industrial: -40°C to +85°C
 - Ext. Commercial: -20° to +70°C
- Excellent Shock and Vibration Immunity
 - Qualified to MIL-STD-883
- High Reliability
- 20x Better MTF Than Quartz Oscillators
- Supply Range of 1.71V to 3.63V
- Short Sample Lead Time: <2 weeks
- Lead Free & RoHS Compliant

Applications

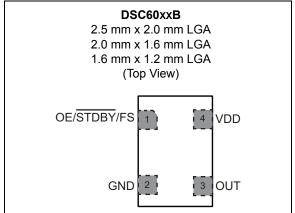
- Low Power/Portable Applications: IoT, Embedded/Smart Devices
- Consumer: Home Healthcare, Fitness Devices, Home Automation
- Automotive: Rear View/Surround View Cameras, Infotainment System (Please refer to DSA60xx Family)
- Industrial: Building/Factory Automation, Surveillance Camera

General Description

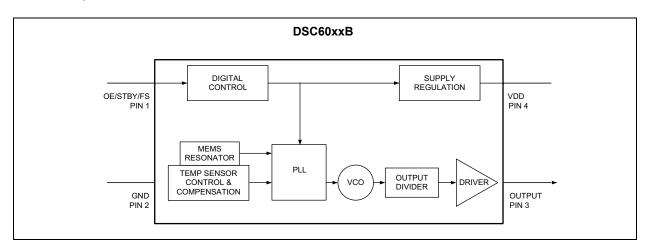
The DSC60xxB family of MEMS oscillators combines industry-leading low-power consumption, ultra-small packages with exceptional frequency stability, and jitter performance over temperature. The single-output DSC60xxB MEMS oscillators are excellent choices for use as clock references in small, battery-powered devices such as wearable and Internet of Things (IoT) devices in which small size, low power consumption, and long-term reliability are paramount. The Automotive Grade AEC-Q100 qualified option is available for this device.

The DSC60xxB family is available in ultra-small 1.6 mm x 1.2 mm, 2.0 mm x 1.6 mm and 2.5 mm x 2.0 mm packages. These packages are "drop-in" replacements for standard 4-pin CMOS quartz crystal oscillators.

Package Types



Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Supply Voltage	
Input Voltage (V _{IN})	
ESD Protection	

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = 1.8V –5% to 3.3V +10%, T_A = -40°C to +125°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Supply Voltage Note 1	V _{DD}	1.71		3.63	V	—	
Active Supply Current	I _{DD}	_	1.3	_	mA	F_{OUT} = 24 MHz, V_{DD} = 1.8V, No Load	
Power Supply Ramp	t _{PU}	0.1	_	100	ms	Note 9	
Standby Supply Current	I _{STBY}	_	1.0	_		V _{DD} = 1.8/2.5V	
Note 2	ISTBY	_	1.5	_	μA	V _{DD} = 3.3V	
Frequency	f ₀	0.002	_	80	MHz	—	
Frequency Stability Note 3	∆f	_		±20 ±25 ±50	ppm	All temp ranges	
	Δf	_		±5		1st year @25°C	
Aging		_	_	±1	ppm	Per year after first year	
Startup Time	t _{SU}	_	_	1.5	ms	From 90% V _{DD} to valid clock output, T = 25°C	
Input Logic Levels	V _{IH}	0.7 x V _{DD}	_	—	V	Input Logic High	
Note 4	V _{IL}	_	_	0.3 x V _{DD}	V	Input Logic Low	
Output Disable Time Note 5	t _{DA}	_	_	200 + 2 Periods	ns	_	
Output Enable Time Note 6	t _{EN}	_		1	μs	_	
Enable Pull-Up Resistor Note 7	_	_	300	_	kΩ	If configured	
Output Logic Levels,	V _{OH}	0.8 x V _{DD}	_	—	V	Output Logic High, I = 1 mA	
Low Drive	V _{OL}	—		0.2 x V _{DD}	V	Output Logic Low, I = –1 mA	

Note 1: Pin 4 V_{DD} should be filtered with 0.1 μ F capacitor.

- 2: Not including current through pull-up resistor on EN pin (if configured).
- 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
- 4: Input waveform must be monotonic with rise/fall time < 10 ms
- 5: Output Disable time takes up to two periods of the output waveform + 200 ns.
- 6: For parts configured with OE, not Standby.
- 7: Output is enabled if pad is floated or not connected.
- 8: Output Duty Cycle will be 40% to 60% when output frequency is between 40 MHz to 60 MHz.
- **9:** Time to reach 90% of target V_{DD}. Power ramp rise must be monotonic.
- 10: Peak-to-peak period jitter is measured over 10,000 cycles.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics	Electrical Characteristics: Unless otherwise indicated, V_{DD} = 1.8V –5% to 3.3V +10%, T_A = -40°C to +125°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Cond	ditions	
		_	2.5	3.5		DSC60x3B Low Drive,	V _{DD} = 1.8V	
Output Transition Time	t _{RX} /t _{FX}	_	1.5	2.2	ns	20% to 80% C _L = 5 pF	V _{DD} = 2.5V/3.3V	
Rise Time/Fall Time	+ / +	_	1.2	2.0		DSC60x1B Std. Drive,	V _{DD} = 1.8V	
	t _{RY} /t _{FY}	_	0.6	1.2	- ns	20% to 80% C _L = 10 pF	V _{DD} = 2.5V/3.3V	
Output Duty Cycle Note 8	SYM	45	_	55	%		_	
	J _{PER}	_	28	_		DSC60x3B Low Drive, F_{OUT} = 27 MHz C_L = 5 pF	V _{DD} = 1.8V	
Devied littler DMC		_	23	_			V _{DD} = 2.5V/3.3V	
Period Jitter, RMS		_	20		_ ps	DSC60x1B Std. Drive, F _{OUT} = 27 MHz C _L = 10 pF	V _{DD} = 1.8V	
		_	18				V _{DD} = 2.5V/3.3V	
		_	120	_		DSC60x3B Low Drive,	V _{DD} = 1.8V	
		_	90	_		F _{OUT} = 27 MHz C _L = 5 pF	V _{DD} = 2.5V/3.3V	
Cycle-to-Cycle Jitter, Peak	J _{Cy–Cy}	_	115	—	_ ps	DSC60x1B Std. Drive,	V _{DD} = 1.8V	
		_	90	_		F _{OUT}	V _{DD} = 2.5V/3.3V	

Note 1: Pin 4 V_{DD} should be filtered with 0.1 μ F capacitor.

- 2: Not including current through pull-up resistor on EN pin (if configured).
- 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
- 4: Input waveform must be monotonic with rise/fall time < 10 ms
- 5: Output Disable time takes up to two periods of the output waveform + 200 ns.
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- 7: Output is enabled if pad is floated or not connected.
- 8: Output Duty Cycle will be 40% to 60% when output frequency is between 40 MHz to 60 MHz.
- **9:** Time to reach 90% of target V_{DD} . Power ramp rise must be monotonic.
- **10:** Peak-to-peak period jitter is measured over 10,000 cycles.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, V_{DD} = 1.8V –5% to 3.3V +10%, T_A = -40°C to +125°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Cone	ditions
Period Jitter,		_	210	_		DSC60x3B Low Drive,	V _{DD} = 1.8V
		_	190	_		F _{OUT} = 27 MHz C _L = 5 pF	V _{DD} = 2.5V/3.3V
Peak-to-Peak, Note 10	JPERPK-PK	_	160	_	ps	DSC60x1B Std. Drive,	V _{DD} = 1.8V
		_	144	_		F _{OUT} = 27 MHz C _L = 10 pF	V _{DD} = 2.5V/3.3V

Note 1: Pin 4 V_{DD} should be filtered with 0.1 μ F capacitor.

- 2: Not including current through pull-up resistor on EN pin (if configured).
- 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
- 4: Input waveform must be monotonic with rise/fall time < 10 ms
- 5: Output Disable time takes up to two periods of the output waveform + 200 ns.
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- 7: Output is enabled if pad is floated or not connected.
- 8: Output Duty Cycle will be 40% to 60% when output frequency is between 40 MHz to 60 MHz.
- 9: Time to reach 90% of target V_{DD} . Power ramp rise must be monotonic.
- **10:** Peak-to-peak period jitter is measured over 10,000 cycles.

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TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Maximum Junction Temperature	TJ	_	_	+150	°C	—
Storage Ambient Temperature Range	Τ _S	-55	_	+150	°C	—
Soldering Temperature			+260	_	°C	40 sec. max.

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The DSC60xxB is a highly configurable device and can be factory programmed in many different ways to meet the customer's needs. Microchip's ClockWorks[®] Configurator http://clockworks.microchip.com/Timing/ must be used to choose the necessary options, create the final part number, data sheet, and order samples. The descriptions of the pins are listed in Table 2-1.

Pin Number	Pin Name	Description			
	OE	Output Enable: H = Active, L = Disabled (High Impedance).			
1	STDBY	Standby: H = Device is active, L = Device is in standby (Low Power Mode).			
FS		Frequency Select: H = Output Frequency 1, L = Output Frequency 2.			
2	GND	Ground.			
3	OUTPUT	Oscillator clock output			
4	VDD	Power Supply: 1.71V to 3.63V.			

TABLE 2-1: DSC60XXB PIN FUNCTION TABLE

An explanation of the different options listed in Table 2-1 follows.

2.1 Pin 1

This is a control pin and may be configured to fulfill one of six different functions. If not actively driven, a 10 k Ω pull-up resistor is recommended.

2.1.1 OUTPUT ENABLE (OE)

Pin 1 may be configured as OE. Oscillator output may be turned on and off according to the state of this pin.

2.1.2 STDBY

Pin 1 may be configured as Standby. When the pin is low, both output buffer and PLL will be off and the device will enter a low power mode.

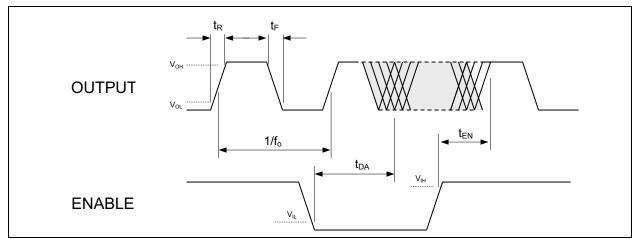
2.1.3 FREQUENCY SELECT (FS)

Pin 1 may be configured as FS. The output may be set to one of two pre-programmed frequencies. The output clock frequencies can only be set to either kHz or MHz. A combination of kHz and MHz cannot be set.

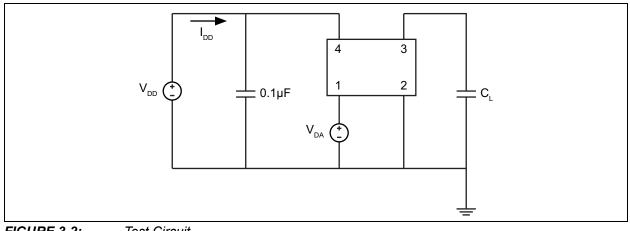
2.2 Pins 2 through 4

Pins 2 and 4 are the supply terminals, GND and VDD respectively. Pin 3 is the clock output, programmable to Standard and Low Drive strength settings. Visit ClockWorks[®] Configurator to customize your device.

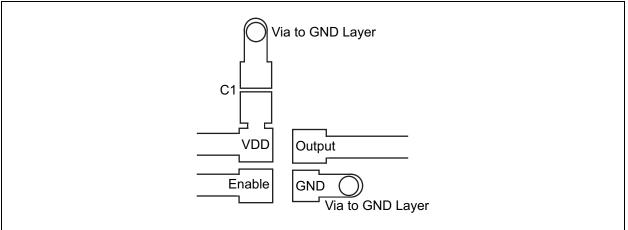
3.0 DIAGRAMS



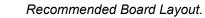
Output Waveform. FIGURE 3-1:



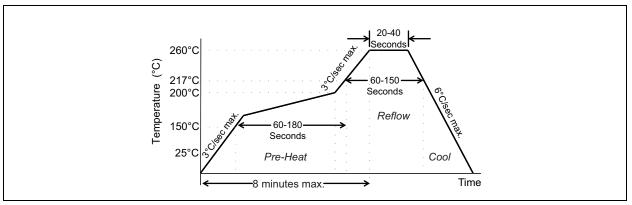


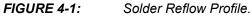






4.0 SOLDER REFLOW PROFILE



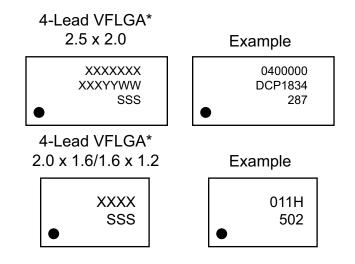


MSL 1 @ 260°C refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec. max.					
Preheat Time 150°C to 200°C	60 to 180 sec.					
Time maintained above 217°C	60 to 150 sec.					
Peak Temperature	255°C to 260°C					
Time within 5°C of actual Peak	20 to 40 sec.					
Ramp-Down Rate	6°C/sec. max.					
Time 25°C to Peak Temperature	8 minutes max.					

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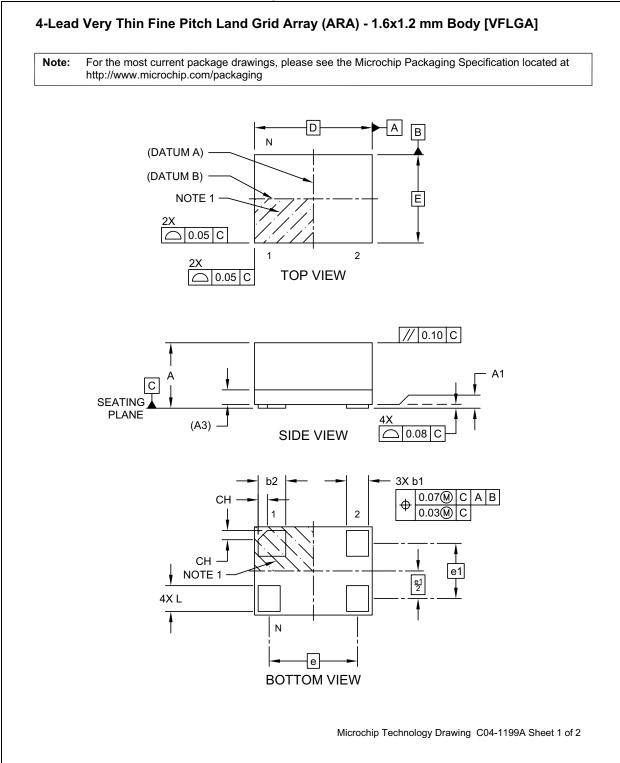
5.0 PACKAGING INFORMATION

5.1 Package Marking Information



Legend:	Y YY WW SSS @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. Pin one index is identified by a dot, delta up, or delta down (triangle
	be carried characters the corpor	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available for customer-specific information. Package may or may not include ate logo. (_) and/or Overbar (⁻) symbol may not be to scale.

4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline

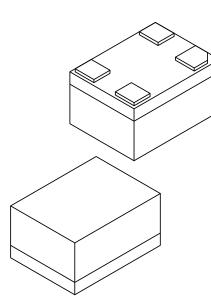


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4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Terminals	Ν		4		
Terminal Pitch	е		1.20 BSC		
Terminal Pitch	e1	0.75 BSC			
Overall Height	Α	0.79	0.84	0.89	
Standoff	A1	0.00	0.02	0.05	
Substrate Thickness (with Terminals)	A3	0.20 REF			
Overall Length	D	1.60 BSC			
Overall Width	Е	1.20 BSC			
Terminal Width	b1	0.25	0.30	0.35	
Terminal Width	b2	0.325	0.375	0.425	
Terminal Length	L	0.30	0.35	0.40	
Terminal 1 Index Chamfer	СН	-	0.125	-	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

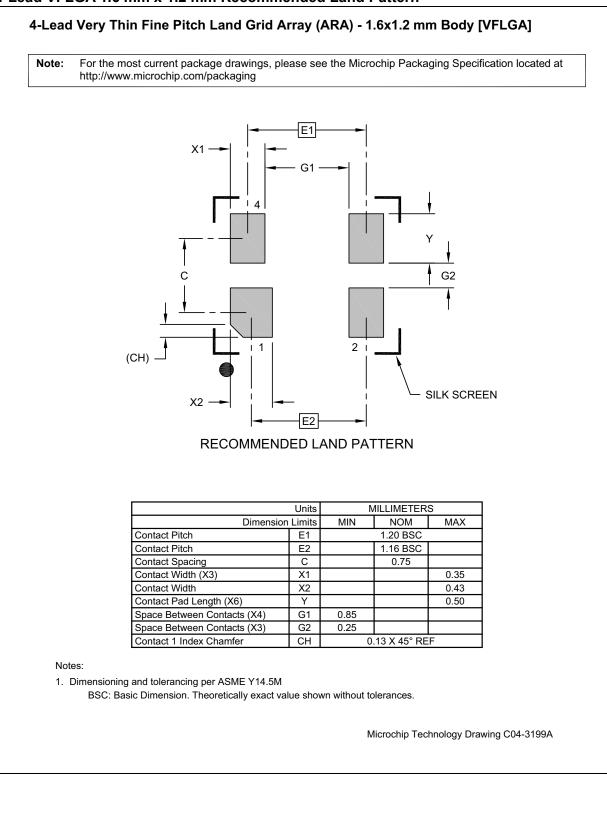
2. Package is saw singulated

3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

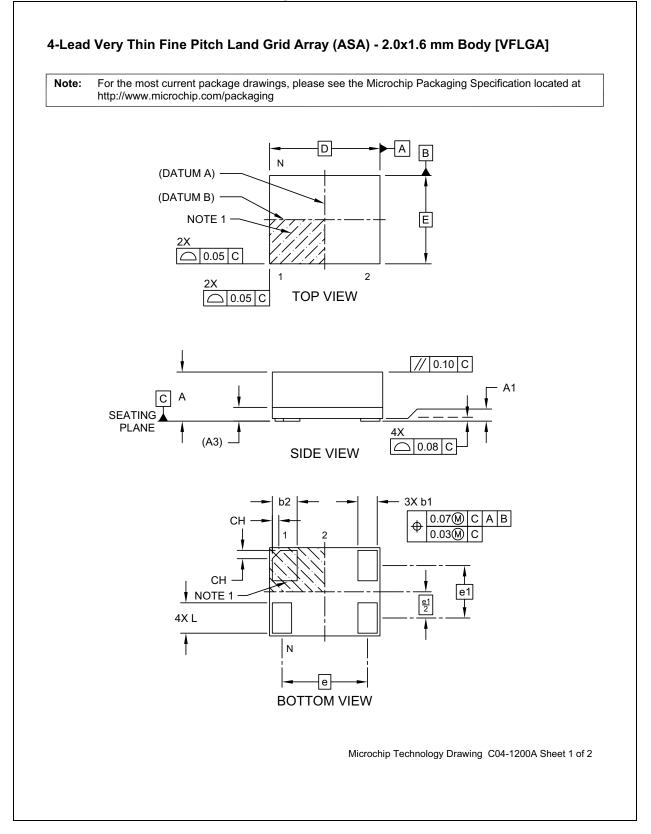
Microchip Technology Drawing C04-1199A Sheet 2 of 2

4-Lead VFLGA 1.6 mm x 1.2 mm Recommended Land Pattern

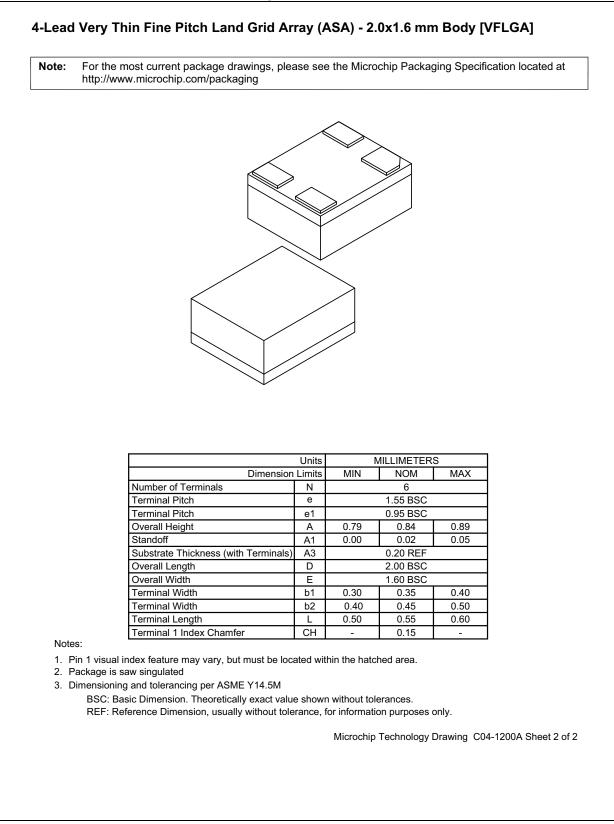


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4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline



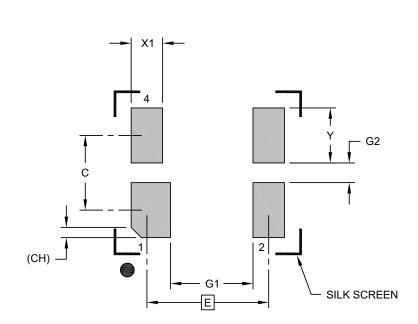
4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline (Continued)



4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS					
Dimension	Limits	MIN	NOM	MAX		
Contact Pitch	E	1.55 BSC				
Contact Spacing	С		0.95			
Contact Width (X4)	X1			0.50		
Contact Width (X2)			0.40			
Contact Pad Length (X6)	Y			0.70		
Space Between Contacts (X4)	G1	1.05				
Space Between Contacts (X3)	0.25					
Contact 1 Index Chamfer	СН	0.13 X 45° REF				

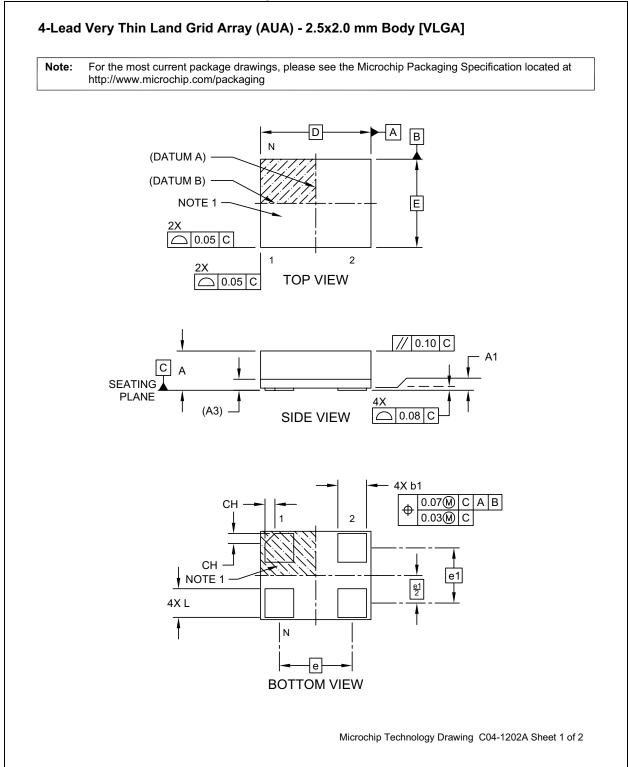
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

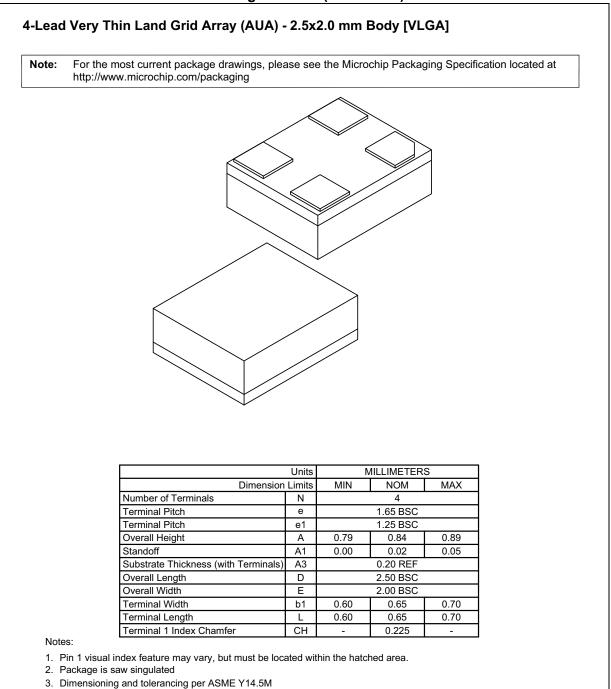
Microchip Technology Drawing C04-3200A

4-Lead VLGA 2.5 mm x 2.0 mm Package Outline



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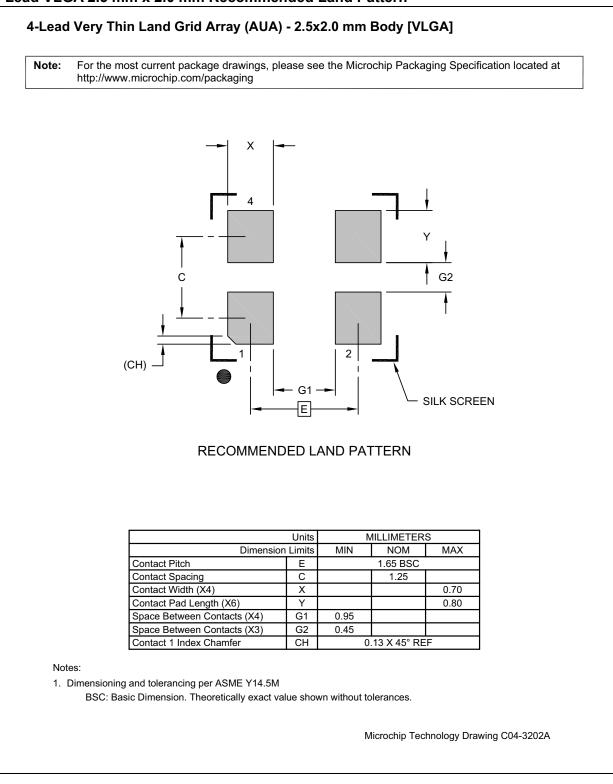
4-Lead VLGA 2.5 mm x 2.0 mm Package Outline (Continued)



BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1202A Sheet 2 of 2

4-Lead VLGA 2.5 mm x 2.0 mm Recommended Land Pattern



NOTES:

APPENDIX A: REVISION HISTORY

Revision A (January 2019)

Initial creation of DSC60xxB Microchip data sheet DS20006133A.

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NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

				Example	es:
Device Pin 1 Qu Definition Dr Stre	ive ength	X X X - XXX.XX I I I I I Temperature Frequency Revision Freque Range Stability	(XX X ency Tape and Reel	Ultra- with li 2.5 m ±20 p	013JI3B-80.0000: -Low Power MEMS Oscillator, Pin1 = STDBY nternal Pull-Up, Low Drive Strength, 4-Lead m x 2.0 mm VLGA, Industrial Temperature, pm Stability, Revision B, 80 MHz Frequency,
Device:	DSC60:	Ultra-Low Power MEMS Oscillator		140/T	
Pin 1 Definition:	Selection 0 1 2 4 5 6	Pin 1Internal Pull-Up RegisterOEPull-upSTDBYPull-upFSPull-upOENoneSTDBYNoneFSNone		 b) DSC6001HE1B-016.0000T: Ultra–Low Power MEMS Oscillator, Pin1 = OE v Internal Pull–Up, Standard Drive Strength, 4-Le 1.6 mm x 1.2 mm VFLGA, Extended Commerci Temp., ±50 ppm Stability, Revision B, 16 MHz Frequency, 1,000/Reel c) DSC6021MI2B-005Q: Ultra–Low Power MEMS Oscillator, Pin1 = Freq with Internal Pull-Up, Standard Drive Strength, 2.0 mm x 1.6 mm VFLGA, Industrial Temperatu ±25 ppm Stability, Revision B, Two Frequencies 	
Output Drive Strength:	1 3	Standard Low			gured through ClockWorks, 100/Bag
Package:	J = M = H =	4-Lead 2.5 mm x 2.0 mm VLGA 4-Lead 2.0 mm x 1.6 mm VFLGA 4-Lead 1.6 mm x 1.2 mm VFLGA			
Temperature Range:	L =	-40°C to +125°C (Automotive) -40°C to +105°C (Extended Industrial) -40°C to +85°C (Industrial) -20°C to +70°C (Extended Commercia		Note 1:	Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip
Frequency Stability:	1 = 2 = 3 =	± 50 ppm ± 25 ppm ± 20 ppm			Sales Office for package availability with the Tape and Reel option.
Revision:	в =	Revision B			
Frequency:	xxxkxxx =	User-Defined Frequency between 001.0000 MHz and 80.0000 MHz User-Defined Frequency between 002.0 and 999.999 kHz Frequency configuration code when pin Configure the part online through Clock configurator.	1 = FS		
Tape and Reel:	<blank>= <blank>= T = B =</blank></blank>	140/Tube (J Package Option) 100/Bag (M & H Package Options) 1,000/Reel 3,000/Reel			

Note 1: Please visit Microchip ClockWorks[®] Configurator Website to configure the part number for customized frequency. http://clockworks.microchip.com/timing/.

NOTES:

Note the following details of the code protection feature on Microchip devices:

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